

D2SB80

800V 1.5A

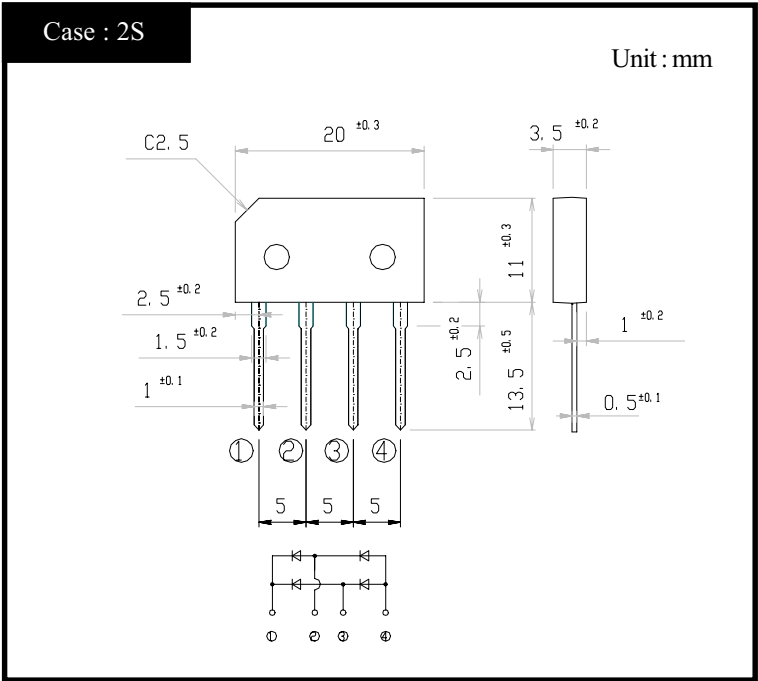
FEATURES

- Thin Single In-Line Package
- High IFSM
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Telecommunication, Factory Automation

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings (If not specified Tl=25°C)

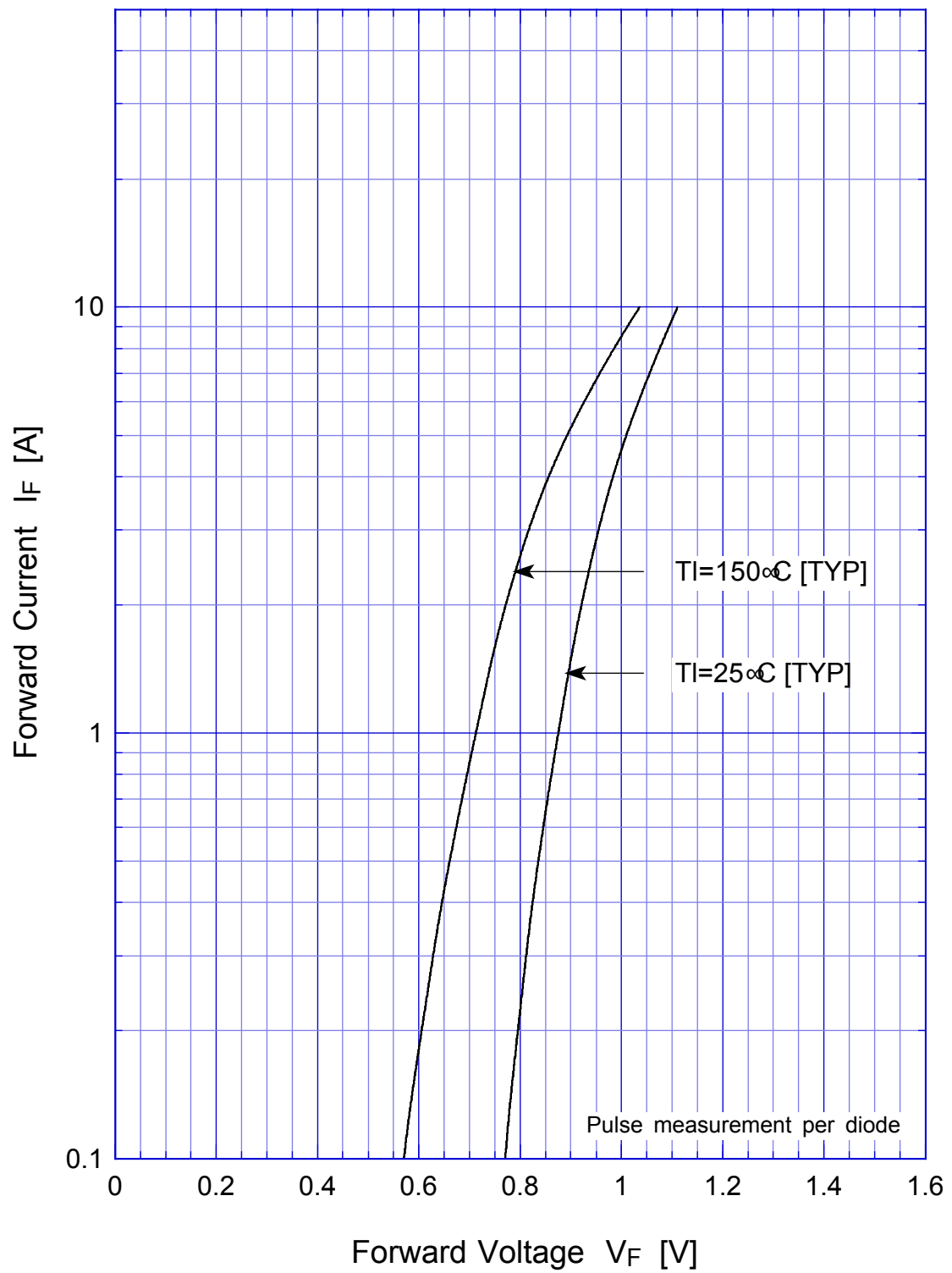
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-40~150	°C
Operating Junction Temperature	Tj		150	°C
Maximum Reverse Voltage	V _{RM}		800	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate, Ta=25°C	1.5	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Tj=25 °C	80	A
Current Squared Time	I ² t	2ms≤t<10ms Tj=25°C	32	A ² s

● Electrical Characteristics (If not specified Tl=25°C)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	IF=0.75A, Pulse measurement,Rating of per diode	Max.1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement,Rating of per diode	Max.10	μA
Thermal Resistance	θ _{jl}	junction to lead	Max.10	°C/W
	θ _{ja}	junction to ambient	Max.47	

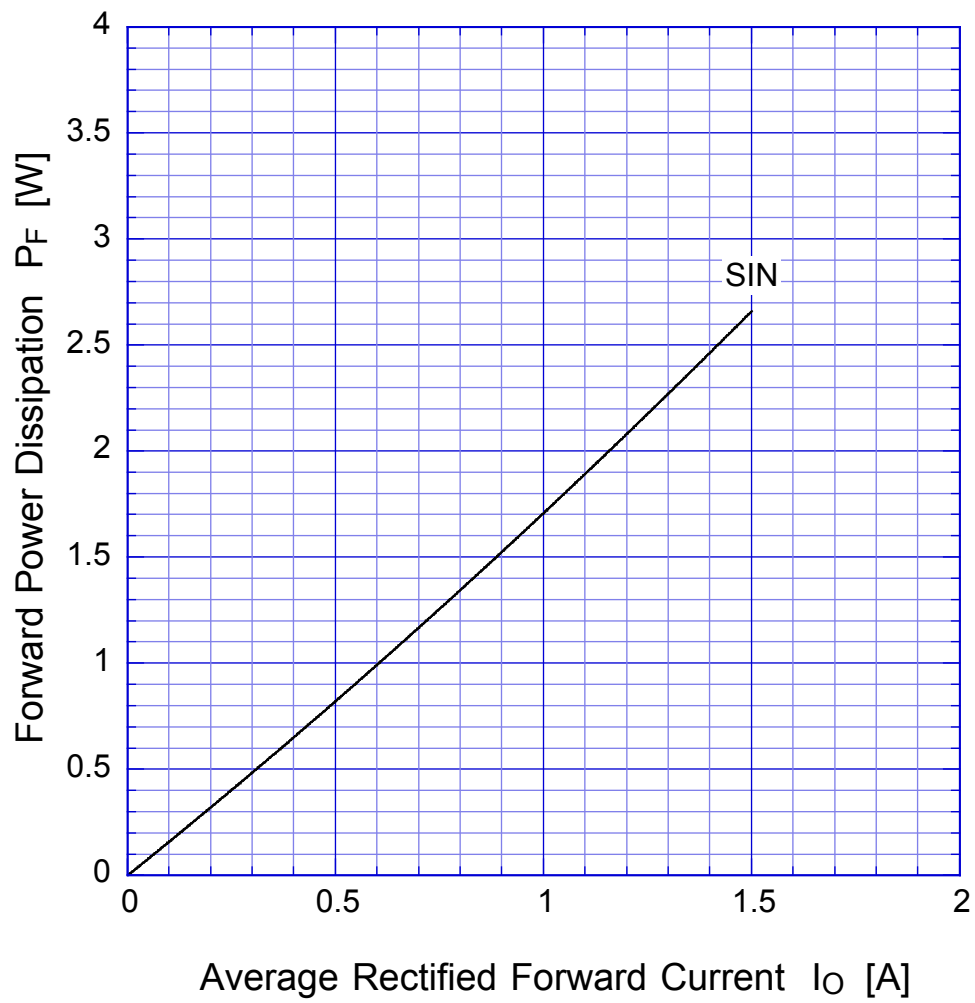
D2SBx

Forward Voltage



D2SBx

Forward Power Dissipation

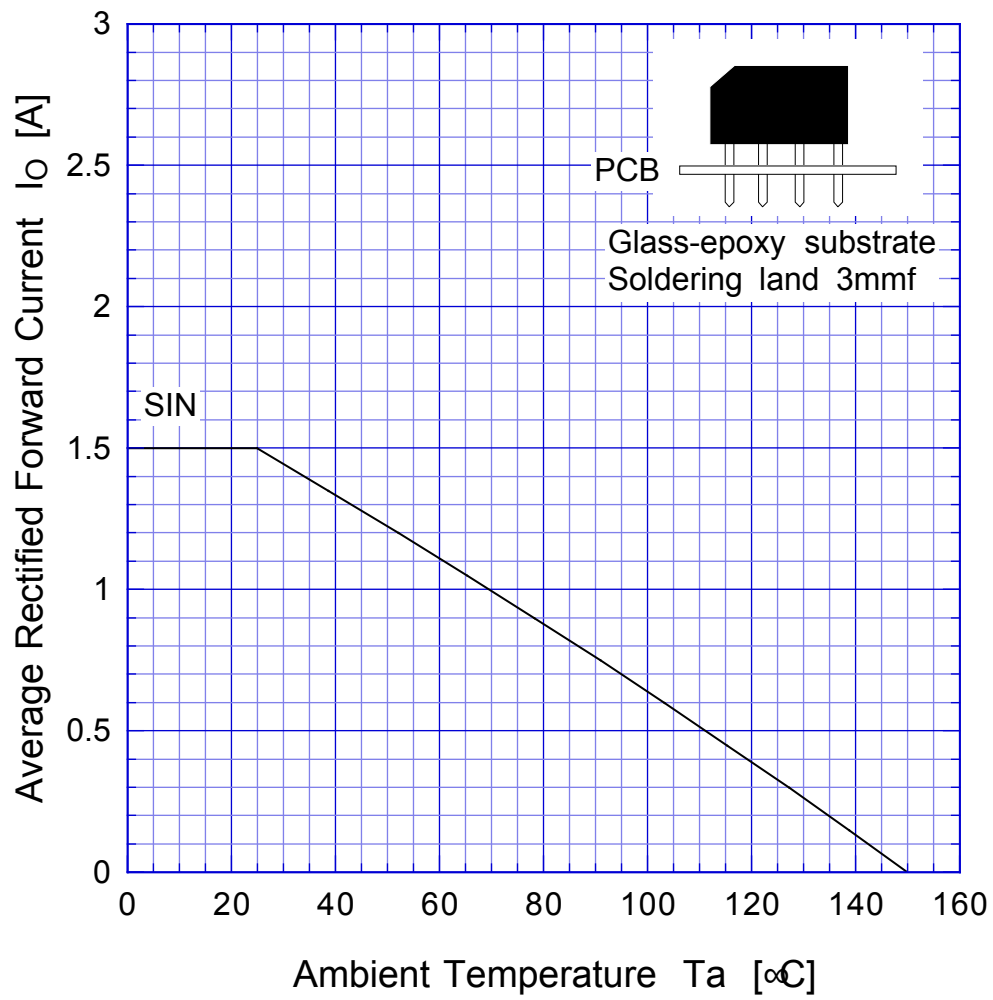


$T_j = 150^\circ\text{C}$

Sine wave

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Derating Curve



Sine wave
R-load
Free in air

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Peak Surge Forward Capability

